

# 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier

SST13LP02



*Preliminary Specifications*

## Features:

- **High Gain:**
  - Typically 27-28 dB gain across 2.4-2.5 GHz
  - Typically 30-34 dB gain across 4.9-5.8 GHz
- **High linear output power:**
  - >25 dBm P1dB (Pulsed single-tone signal) across 2.4-2.5 GHz
  - Meets 802.11b OFDM ACPR requirement up to 21.5 dBm across 2.4-2.5 GHz
  - Meets 802.11g OFDM ACPR requirement up to 22 dBm across 2.4-2.5 GHz
  - Added EVM~4% up to 19 dBm for 54 Mbps 802.11g signal across 2.4-2.5 GHz
  - >25 dBm P1dB (Pulsed single-tone signal) across 4.9-5.8 GHz
  - Meets 802.11a OFDM ACPR requirement up to 22 dBm across 4.9-5.8GHz
  - Added EVM~4% up to 18 dBm for 54 Mbps 802.11a signal across 4.9-5.8GHz
- **High power-added efficiency/Low operating current for 802.11a/b/g applications**
  - ~220 mA @  $P_{OUT} = 22$  dBm for 802.11g
  - ~205 mA @  $P_{OUT} = 21.5$  dBm for 802.11b
  - ~380 mA @  $P_{OUT} = 22$  dBm for 802.11a
- **Built-in Ultra-low  $I_{REF}$  power-up/down control**
  - $I_{REF} < 2$  mA
- **Low idle current**
  - ~55 mA  $I_{CQ}$  (802.11b/g)
  - ~135 mA  $I_{CQ}$  (802.11a)
- **High-speed power-up/down**
  - Turn on/off time (10%-90%) <100 ns
  - Typical power-up/down delay with driver delay included <200 ns
- **High temperature stability**
  - ~2/1 dB gain/power variation between 0°C to +85°C across 2.4-2.5 GHz
  - ~8/2 dB gain/max linear power variation between 0°C to +85°C across 4.9-5.8 GHz
  - ~1 dB detector variation over 0°C to +85°C
- **Low shut-down current (< 0.1  $\mu$ A)**
- **On-chip power detection**
- **20 dB dynamic range on-chip power detection**
- **Simple input/output matching**
- **Packages available**
  - 24-lead WQFN (4mm x 4mm)
  - Non-Pb (lead-free) packages available

## Applications:

- **WLAN (IEEE 802.11a/g/b)**
- **Japanese WLAN**
- **HyperLAN2**
- **Multimedia**
- **Home RF**
- **Cordless phones**

## Product Description

The SST13LP02 is a high-efficiency, dual-band power amplifier based on the highly-reliable InGaP/GaAs HBT technology.

The SST13LP02 can be easily configured for high-power applications with superb power-added efficiency while operating over the 802.11a/b/g frequency band for U.S., European, and Japanese markets (2.4-2.5 GHz and 4.9-5.8 GHz).

The SST13LP02 has excellent linearity, typically ~4% added EVM at 19 dBm output power, which is essential for 54 Mbps 802.11g operation while meeting 802.11g spectrum mask at 22 dBm and 802.11b spectrum mask at 21.5 dBm. For 802.11a operation, the SST13LP02 has demonstrated typically ~4% added EVM at 18 dBm output power while meeting 802.11a spectrum mask at 22 dBm. The

SST13LP02 also has wide-range (>15 dB), temperature-stable (~1.5 dB over 85°C), single-ended power detectors which lower users' cost on power control.

The power amplifier IC also features easy board-level usage along with high-speed power-up/down control. Ultra-low reference current (total  $I_{REF} < 2$  mA) makes the SST13LP02 controllable by an on/off switching signal directly from the baseband chip. These features, coupled with low operating current, make the SST13LP02 ideal for the final stage power amplification in both battery-powered 802.11a/b/g WLAN transmitters and access point applications.

The SST13LP02 is offered in a 24-contact WQFN package. See Figure 2 for pin assignments and Table 1 for pin descriptions.



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

### Functional Blocks

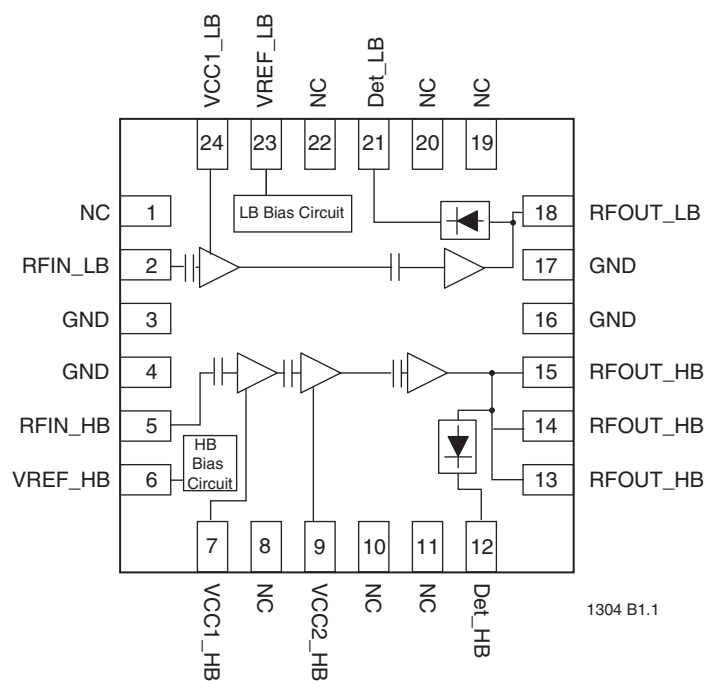


FIGURE 1: Functional Block Diagram

## Pin Assignments

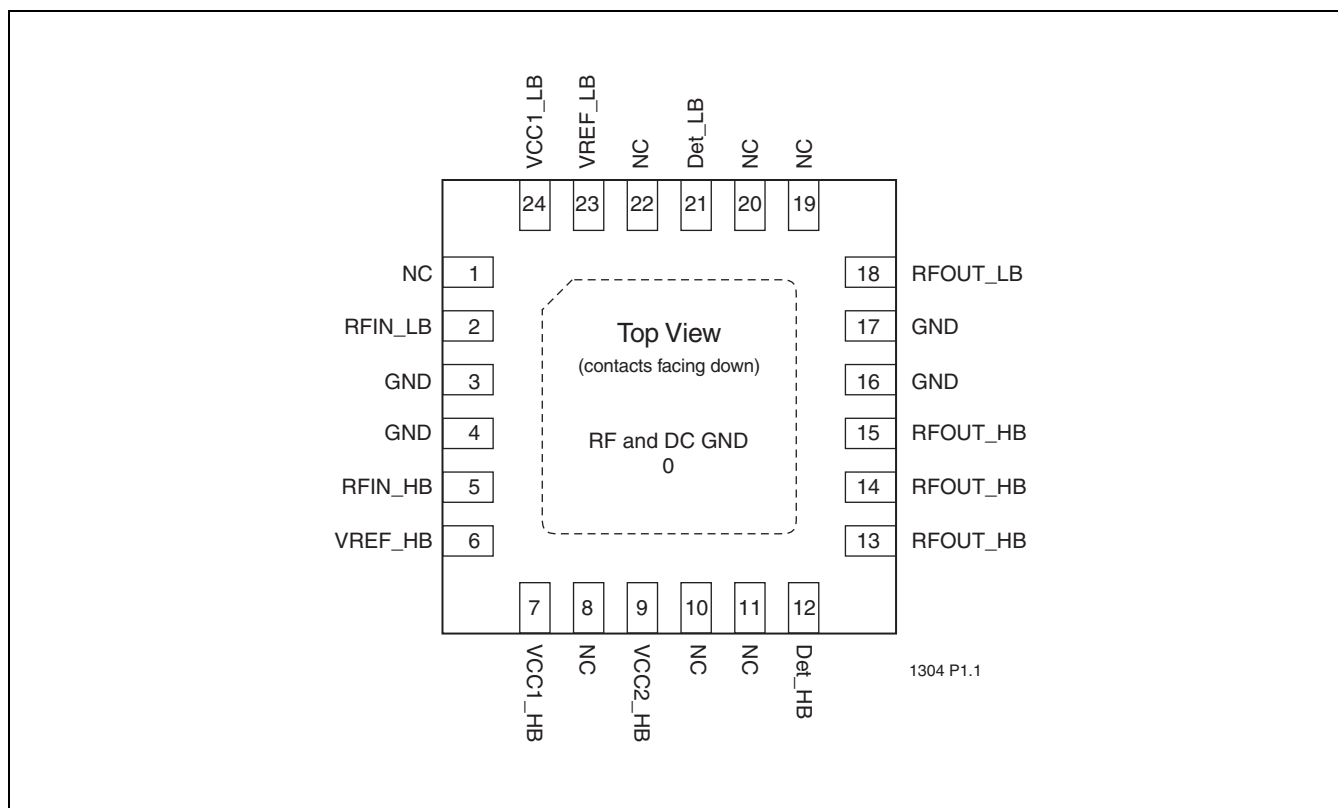


FIGURE 2: Pin Assignments for 16-contact WQFN



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

### Pin Descriptions

**TABLE 1: Pin Description**

| Symbol              | Pin No. | Pin Name      | Type  | Function                                 |
|---------------------|---------|---------------|-------|------------------------------------------|
| GND                 | 0       | Ground        |       | Ground Pad                               |
| NC                  | 1       | No Connection |       | Unconnected Pin                          |
| RFin_LB             | 2       |               | I     | RF Input for Low Band, DC decoupled      |
| GND                 | 3       | Ground        |       | Ground Pin                               |
| GND                 | 4       | Ground        |       | Ground Pin                               |
| RFin_HB             | 5       |               | I     | RF Input for High Band, DC decoupled     |
| V <sub>REF_HB</sub> | 6       | Power Supply  | PWR   | Idle Current Control for High Band       |
| V <sub>cc1_HB</sub> | 7       | Power Supply  | PWR   | Vcc Power Supply for High Band           |
| NC                  | 8       | No Connection |       | Unconnected Pin                          |
| V <sub>cc2_HB</sub> | 9       | Power Supply  | PWR   | Vcc Power Supply for High Band           |
| NC                  | 10      | No Connection |       | Unconnected Pin                          |
| NC                  | 11      | No Connection |       | Unconnected Pin                          |
| Det_HB              | 12      |               | O     | Detector Voltage Output for High Band    |
| RFout_HB            | 13      | Power Supply  | O/PWR | RF Output/Vcc power supply for High Band |
| RFout_HB            | 14      | Power Supply  | O/PWR | RF Output/Vcc power supply for High Band |
| RFout_HB            | 15      | Power Supply  | O/PWR | RF Output/Vcc power supply for High Band |
| GND                 | 16      | Ground        |       | Ground Pin                               |
| GND                 | 17      | Ground        |       | Ground Pin                               |
| RFout_LB            | 18      | Power Supply  | O/PWR | RF Output/Vcc power supply for Low Band  |
| NC                  | 19      | No Connection |       | Unconnected Pin                          |
| NC                  | 20      | No Connection |       | Unconnected Pin                          |
| Det_LB              | 21      |               | O     | Detector Voltage Output for Low Band     |
| NC                  | 22      | No Connection |       | Unconnected Pin                          |
| V <sub>REF_LB</sub> | 23      | Power Supply  | PWR   | Idle Current Control for Low Band        |
| V <sub>cc1_LB</sub> | 24      | Power Supply  | PWR   | Vcc Power Supply for Low Band            |

T1.2 1304

## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02



Preliminary Specifications

### ELECTRICAL SPECIFICATIONS

The AC and DC specifications for the power amplifier interface signals. Refer to Tables 2 and 4 for the DC voltage and current specifications. Refer to Figures 3 through 22 for the RF performance.

**Absolute Maximum Stress Ratings** Applied conditions greater than those listed under “Absolute Maximum Stress Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these conditions or conditions greater than those defined in the operational sections of this data sheet is not implied. Exposure to absolute maximum stress rating conditions may affect device reliability.

|                                        |                 |
|----------------------------------------|-----------------|
| Supply Voltage ( $V_{CC}$ )            | -0.3V to +4.0V  |
| Reference Voltage ( $V_{REF}$ )        | -0.3V to +3.3V  |
| DC supply current ( $I_{CC}$ )         | 500 mA          |
| Operating Temperature ( $T_A$ )        | -40°C to +85°C  |
| Storage Temperature ( $T_{STG}$ )      | -40°C to +120°C |
| Maximum Junction Temperature ( $T_J$ ) | +150°C          |



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

### For 802.11b/g Operation

**TABLE 2: DC Electrical Characteristics**

| Symbol           | Parameter                                                      | Min. | Typ | Max. | Unit | Test Conditions |
|------------------|----------------------------------------------------------------|------|-----|------|------|-----------------|
| V <sub>CC</sub>  | Supply Voltage                                                 | 3.0  | 3.3 | 3.6  | V    |                 |
| I <sub>CC</sub>  | Supply Current<br>for 802.11g, 22 dBm<br>for 802.11b, 21.5 dBm |      |     |      |      |                 |
|                  |                                                                |      | 220 |      | mA   |                 |
|                  |                                                                |      | 205 |      | mA   |                 |
| I <sub>CQ</sub>  | Idle current for 802.11g to meet EVM<4% @ 18 dBm               |      | 55  |      | mA   |                 |
| I <sub>OFF</sub> | Shut down current                                              |      |     | 0.1  | μA   |                 |
| V <sub>REG</sub> | Reference Voltage with drop resistors                          |      | 2.9 |      | V    |                 |

T2.1 1304

**TABLE 3: AC Electrical Characteristics for Configuration**

| Symbol            | Parameter                                                               | Min. | Typ | Max. | Unit |
|-------------------|-------------------------------------------------------------------------|------|-----|------|------|
| F <sub>L-U</sub>  | Frequency range                                                         | 2400 |     | 2485 | MHz  |
| G                 | Small signal gain                                                       | 25   |     |      | dB   |
| G <sub>VAR1</sub> | Gain variation over band (2400-2485 MHz)                                |      |     | ±0.5 | dB   |
| G <sub>VAR2</sub> | Gain ripple over channel (20 MHz)                                       |      | 0.2 |      | dB   |
| ACPR              | Output power level meet 11b spectrum mask                               | 21   |     |      | dBm  |
|                   | Output power level meet 11g OFDM 54 Mbps spectrum mask                  | 21   |     |      | dBm  |
| Added EVM         | Added EVM @ Pout = 19 dBm with (54 Mbps 11g OFDM)                       |      |     | 4    | %    |
| 2f                | 2nd Harmonics at Pout=18 dBm (54 Mbps 11g OFDM)                         |      | -45 |      | dBc  |
| 3f                | 3rd Harmonics at Pout=18 dBm (54 Mbps 11g OFDM)                         |      | -50 |      | dBc  |
| ACPR1             | Adjacent Channel Power Rejection at Pout=18 dBm (54 Mbps 11g OFDM)      |      | -35 |      | dBc  |
| ACPR2             | Alt. Adjacent Channel Power Rejection at Pout=18 dBm (54 Mbps 11g OFDM) |      | -45 |      | dBc  |

T3.1 1304



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

### For 802.11a Operation

**TABLE 4: DC Electrical Characteristics**

| Symbol                 | Parameter                                     | Min. | Typ | Max. | Unit |
|------------------------|-----------------------------------------------|------|-----|------|------|
| V <sub>CC</sub>        | Supply Voltage                                | 3.0  | 3.3 | 3.6  | V    |
| I <sub>CC</sub>        | Supply Current                                |      |     |      |      |
|                        | for 802.11a, 22 dBm at V <sub>CC</sub> = 3.3V |      | 380 |      | mA   |
| I <sub>CQ</sub>        | V <sub>CC</sub> quiescent current             |      | 135 |      | mA   |
| I <sub>OFF</sub>       | Shut down current                             |      |     | 1.0  | μA   |
| V <sub>REG</sub>       | Reference Voltage with drop resistors         |      | 2.9 |      | V    |
| Total I <sub>REG</sub> | Total Reference Current                       |      |     | 2    | mA   |

T4.1 1304

**TABLE 5: AC Electrical Characteristics for Configuration**

| Symbol           | Parameter                                                               | Min. | Typ | Max. | Unit |
|------------------|-------------------------------------------------------------------------|------|-----|------|------|
| F <sub>L-U</sub> | Frequency range                                                         | 4920 |     | 5805 | MHz  |
| G                | Small signal gain across 4.9~5.8GHz                                     | 26   |     |      | dB   |
| G <sub>VAR</sub> | Gain variation over band (4.9-5.8 MHz)                                  |      | 5.0 |      | dB   |
|                  | Gain variation over band (4.9-5.35 MHz)                                 |      | 1.0 |      | dB   |
|                  | Gain variation over band (5.7-5.8 MHz)                                  |      | 1.0 |      | dB   |
|                  | Gain variation over channel (20 MHz)                                    |      | 0.2 |      | dB   |
| Added EVM        | Added EVM @ Pout=18 dBm (54 Mbps 11a OFDM)                              |      |     | 4    | %    |
| ACPR             | Output power level with 802.11a mask compliance across 4.9-5.8 GHz      | 21   |     |      | dBm  |
| 2f               | 2nd Harmonics at Pout=18 dBm (54 Mbps 11a OFDM)                         |      | -45 |      | dBc  |
| 3f               | 3rd Harmonics at Pout=18 dBm (54 Mbps 11a OFDM)                         |      | -50 |      | dBc  |
| ACPR1            | Adjacent Channel Power Rejection at Pout=18 dBm (54 Mbps 11a OFDM)      |      | -35 |      | dBc  |
| ACPR2            | Alt. Adjacent Channel Power Rejection at Pout=18 dBm (54 Mbps 11a OFDM) |      | -50 |      | dBc  |

T5.1 1304



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

### Typical Low Band Performance for 802.11B/G

TEST CONDITIONS:  $V_{CC} = 3.3V$ ,  $T_A = 25^\circ C$ ,  $V_{REF\_LB} = 2.9V$  UNLESS OTHERWISE NOTED

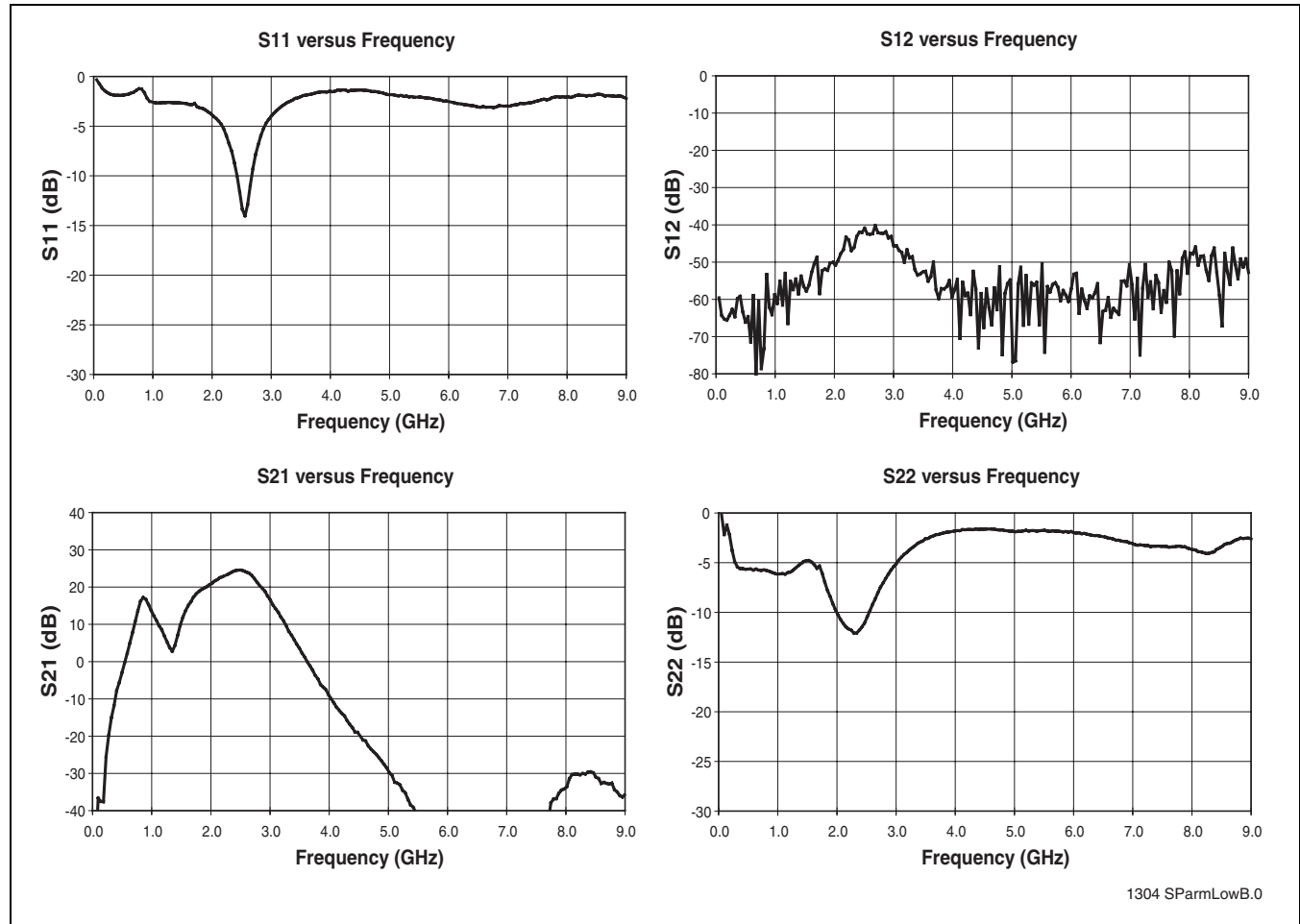


FIGURE 3: Low Band S-Parameters

Test Conditions: VCC = 3.3V, 54 Mbps 802.11g OFDM signal

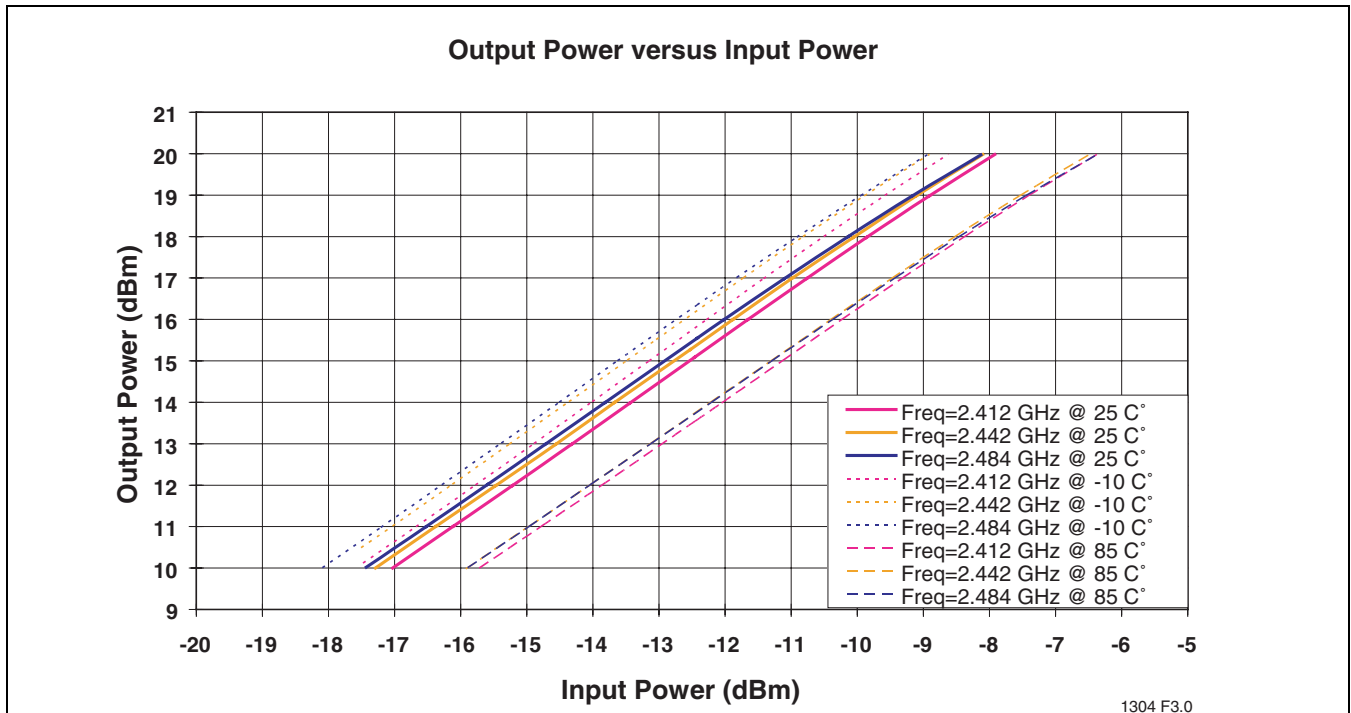


FIGURE 4: Low Band Output Power Versus Input Power

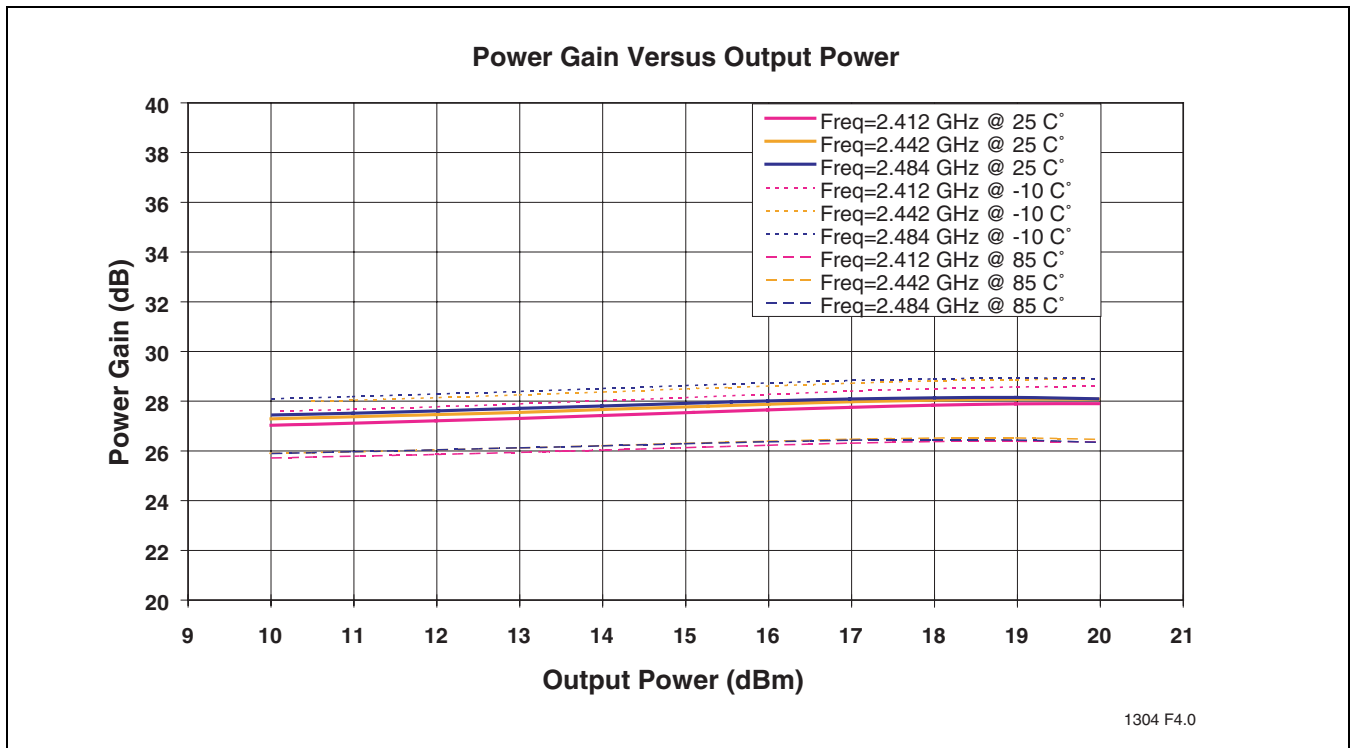


FIGURE 5: Low Band Power Gain versus Output Power



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

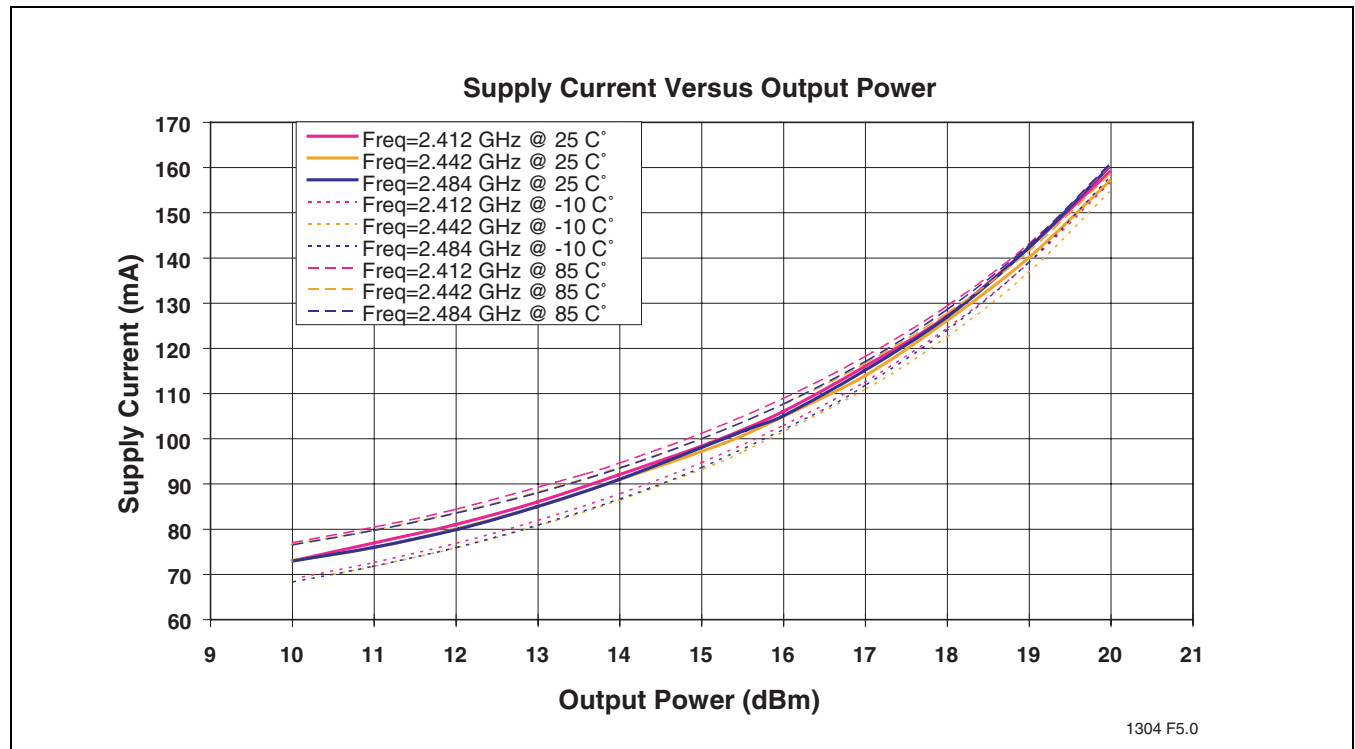


FIGURE 6: Low Band Supply Current versus Output Power

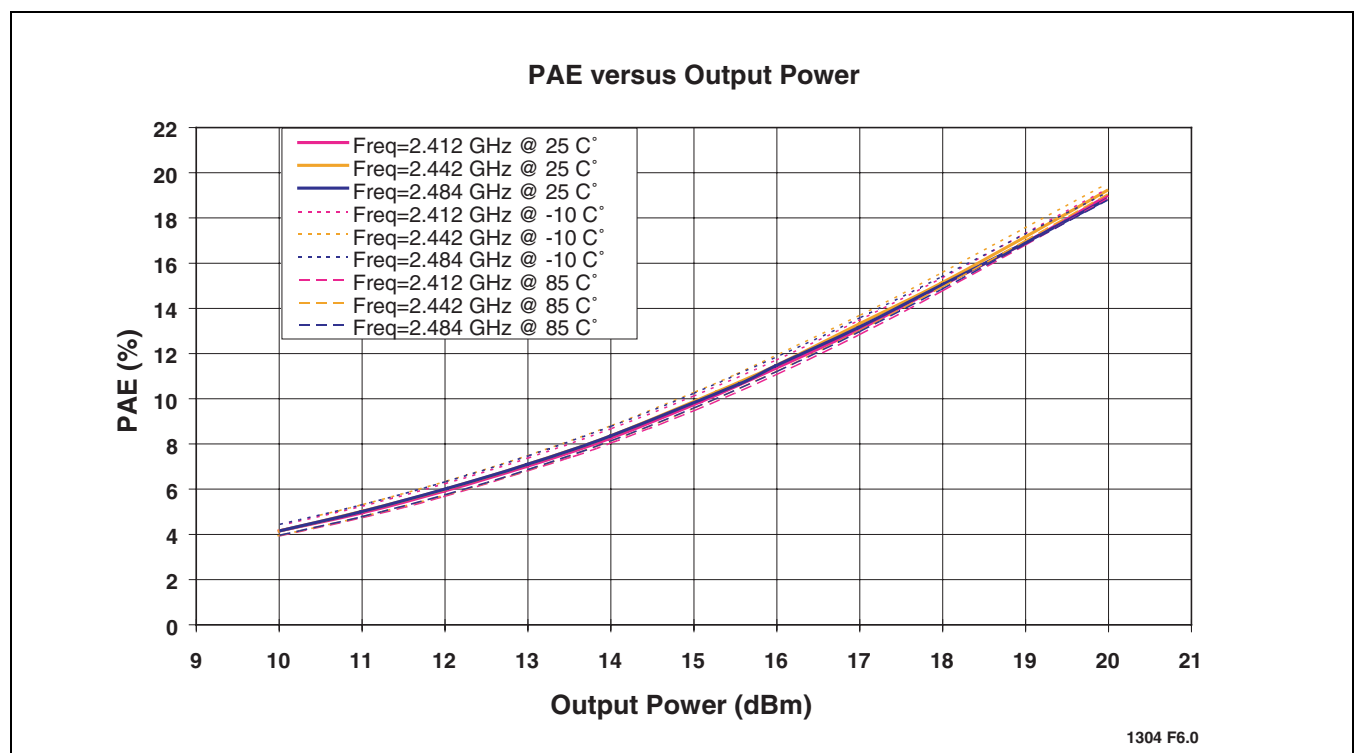


FIGURE 7: Low Band PAE versus Output Power

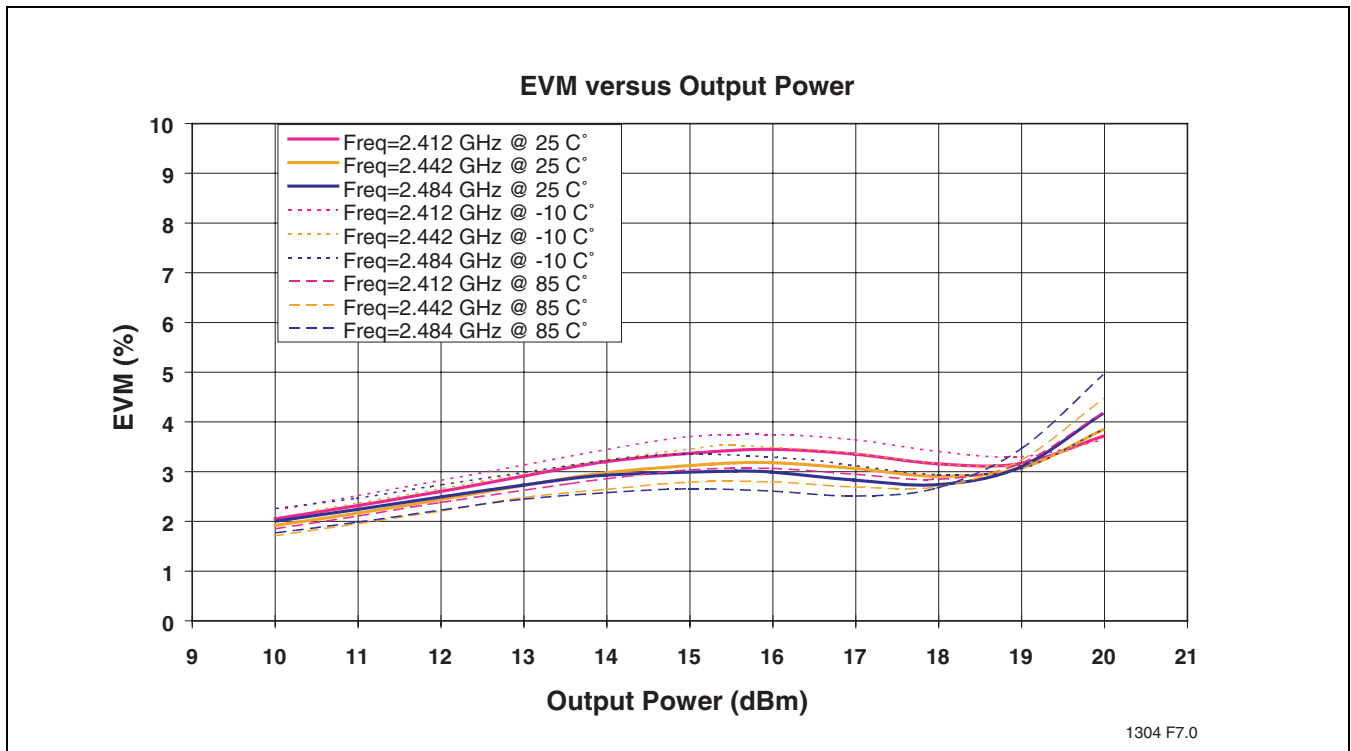


FIGURE 8: Low Band EMV Versus Output Power

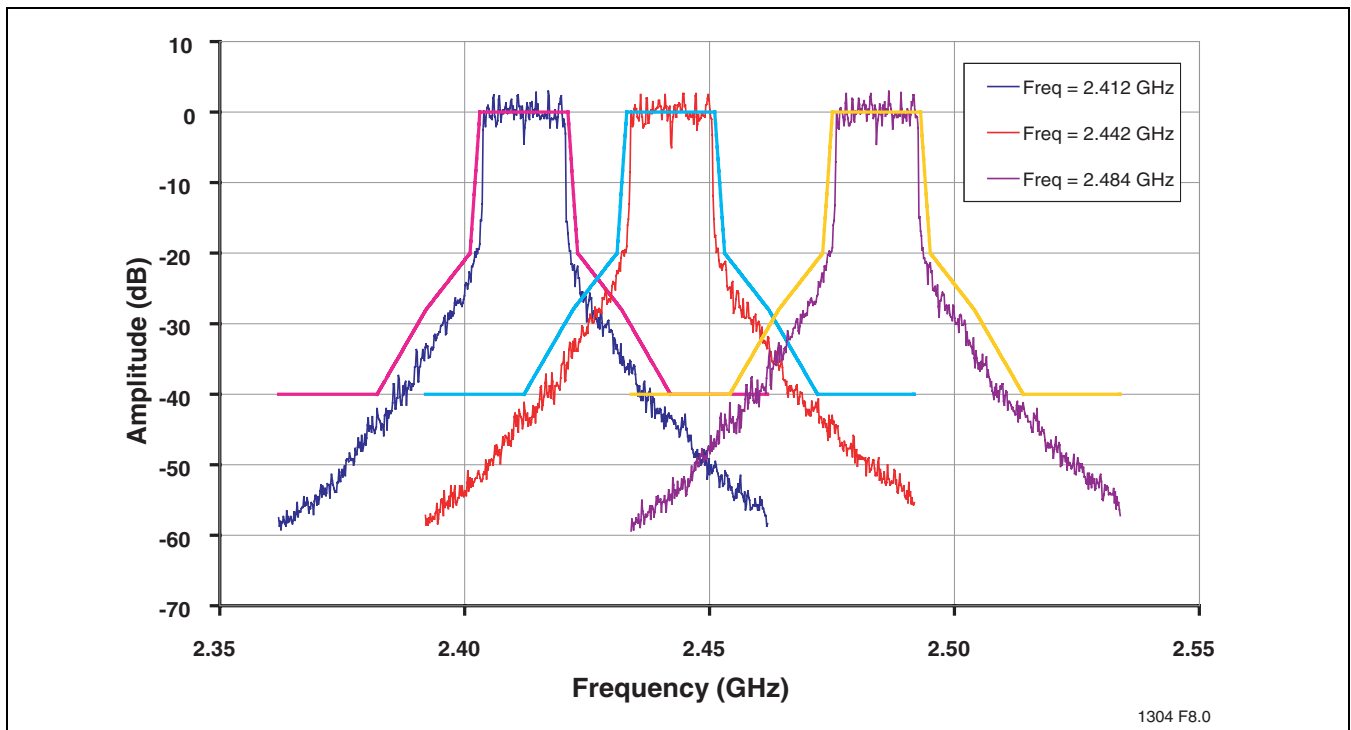


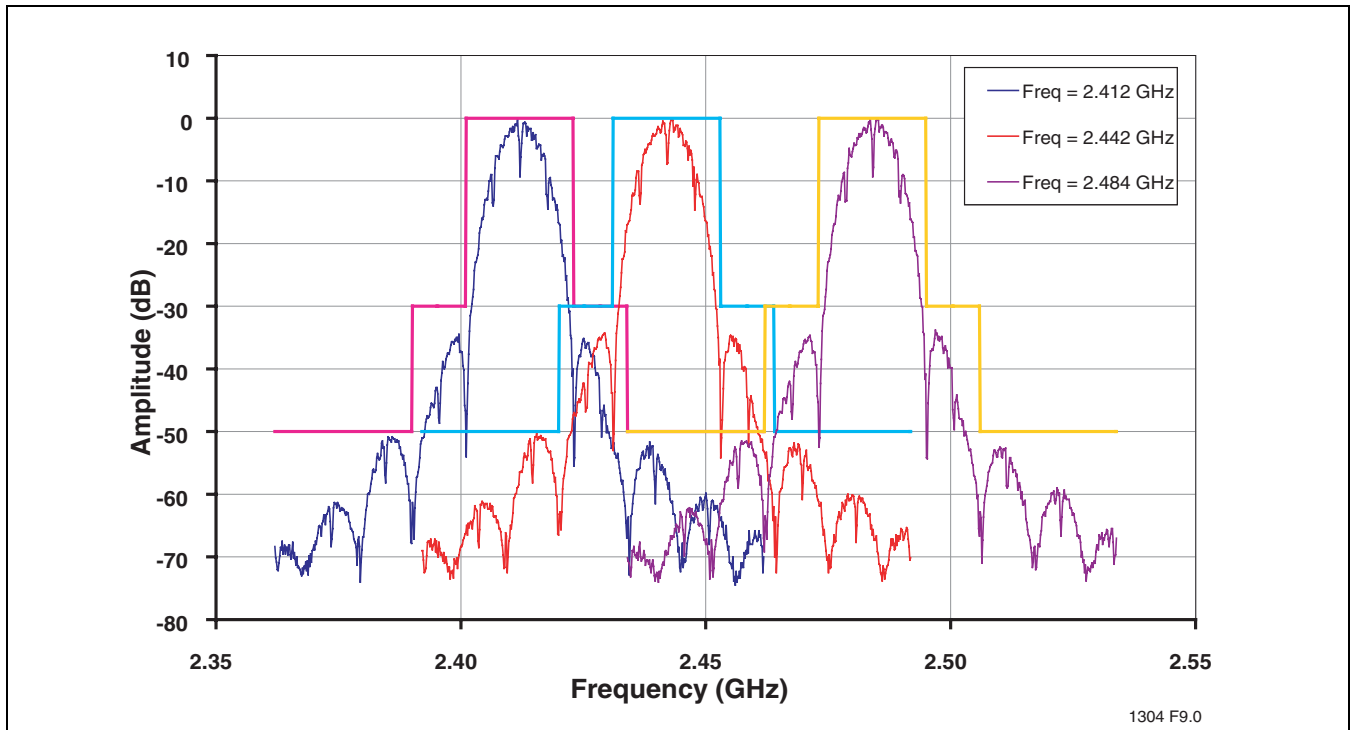
FIGURE 9: Low Band 802.11b Spectrum Mask at 22 dBm with DC Current of 220 mA



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

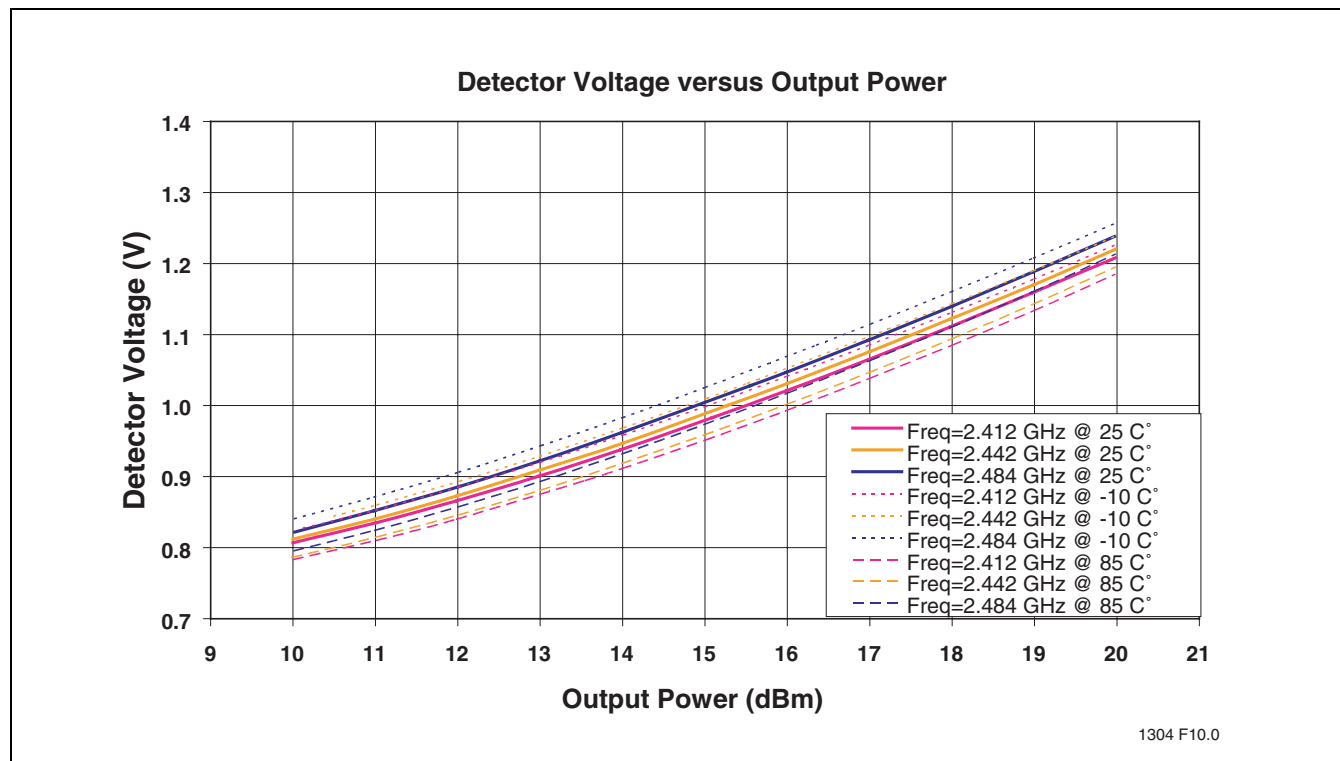
**Test Conditions:**  $V_{CC} = 3.3V$ ,  $T_A = 25^{\circ}C$ , 1 Mbps 802.11b CCK Signal



**FIGURE 10: Low Band 802.11b Spectrum Mask at 21.5 dBm with DC Current of 205 mA**

### Low Band Power Detector characteristics

Test Conditions:  $V_{CC} = 3.3V$ ,  $V_{REG\_LB} = 2.85V$ ,  $T_A = 25^{\circ}C$ , 54 Mbps 802.11g OFDM Signal



**FIGURE 11: Low Band Detector Voltage versus output power**



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

### Typical High Band Performance for 802.11a

Test Conditions:  $V_{CC} = 3.3V$ ,  $T_A = 25^{\circ}C$ ,  $V_{REF\_HB} = 2.9V$  unless otherwise noted

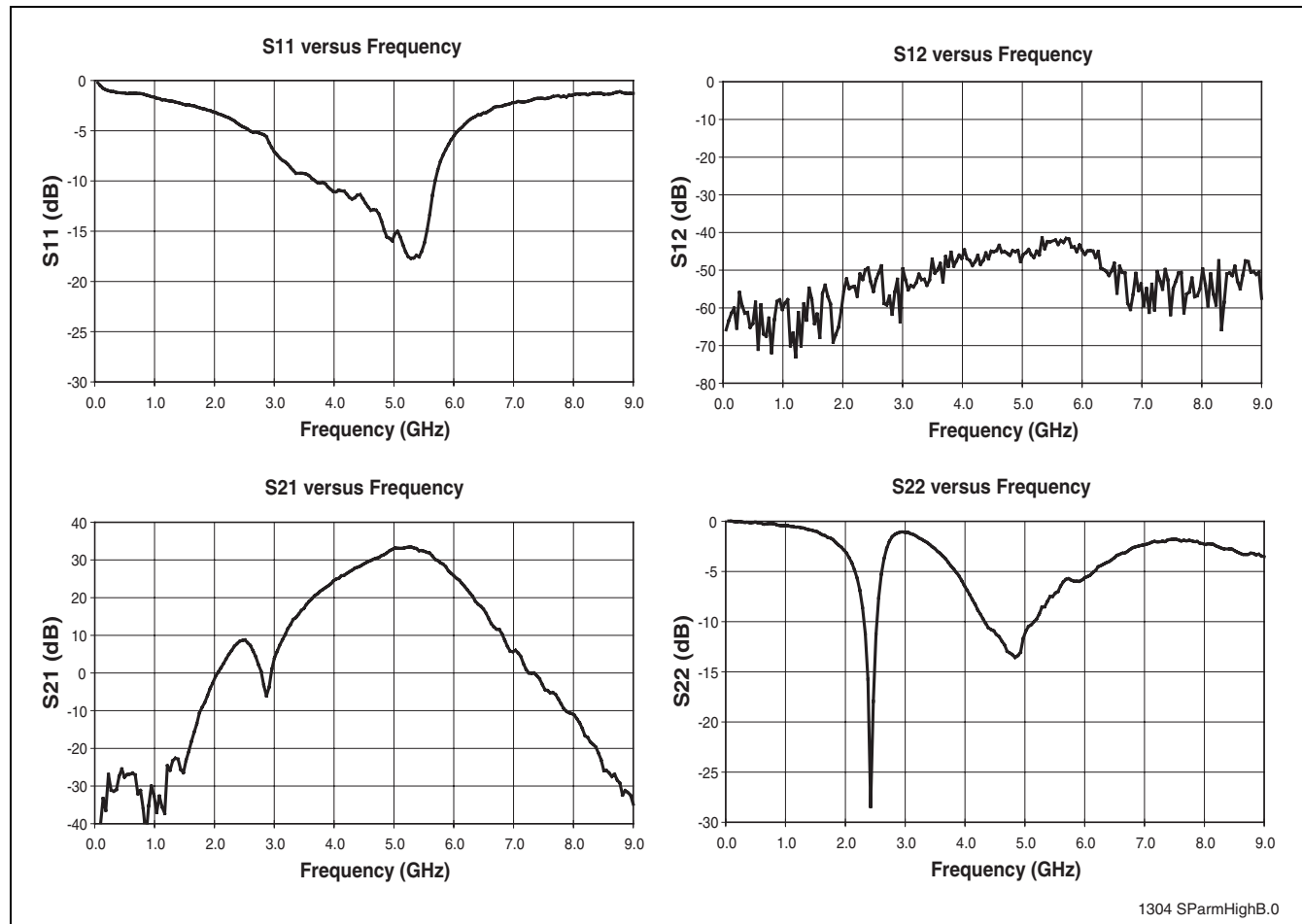


FIGURE 12: High Band S-Parameters

Typical Performance characteristics for 802.11A

Test Conditions: VCC = 3.3V, 54 Mbps 802.11a OFDM Signal

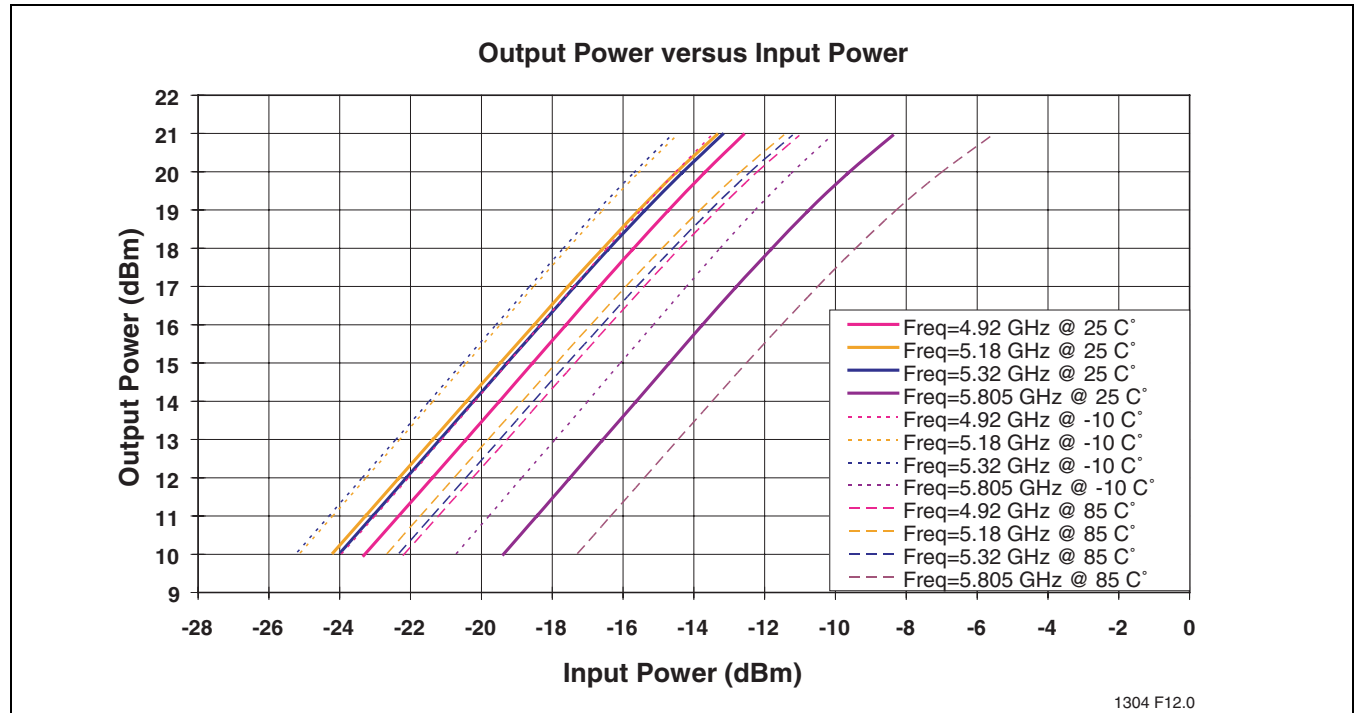


FIGURE 13: High Band Output Power Versus Input Power

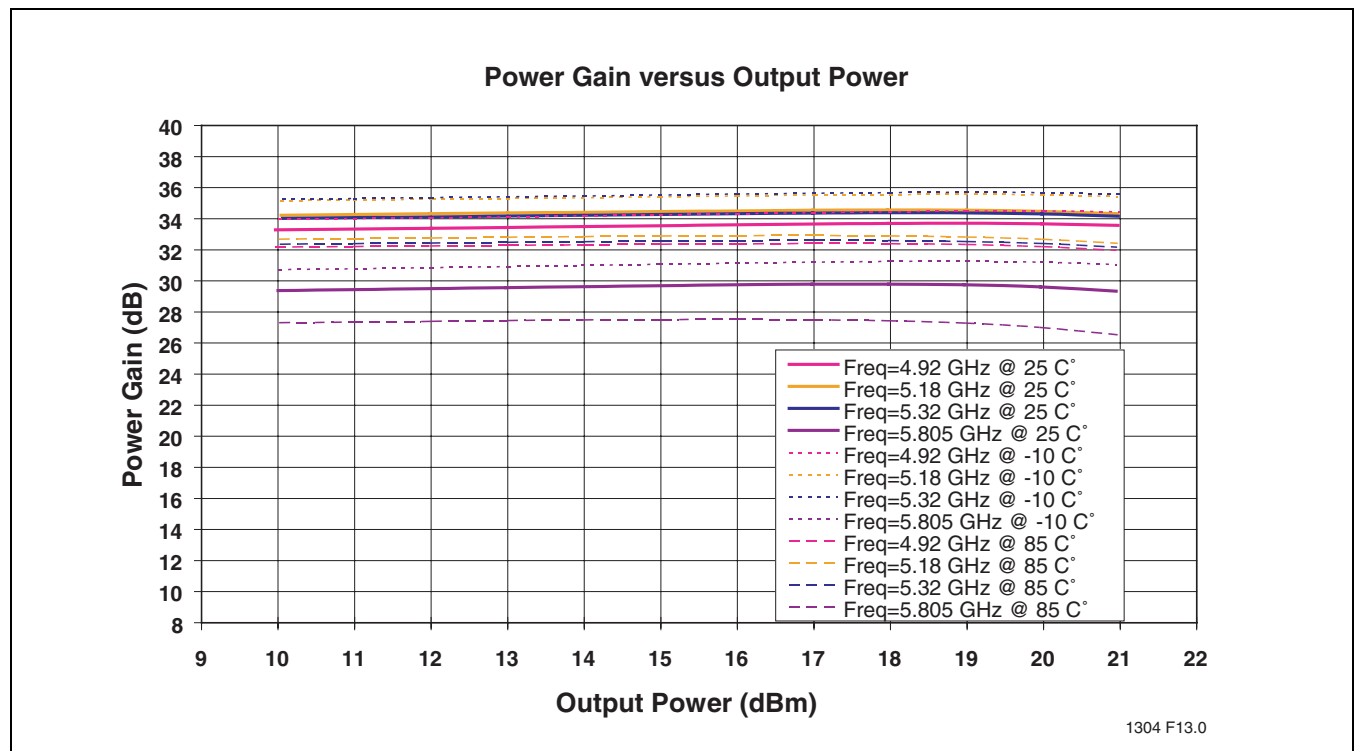


FIGURE 14: High Band Power Gain versus Output Power



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

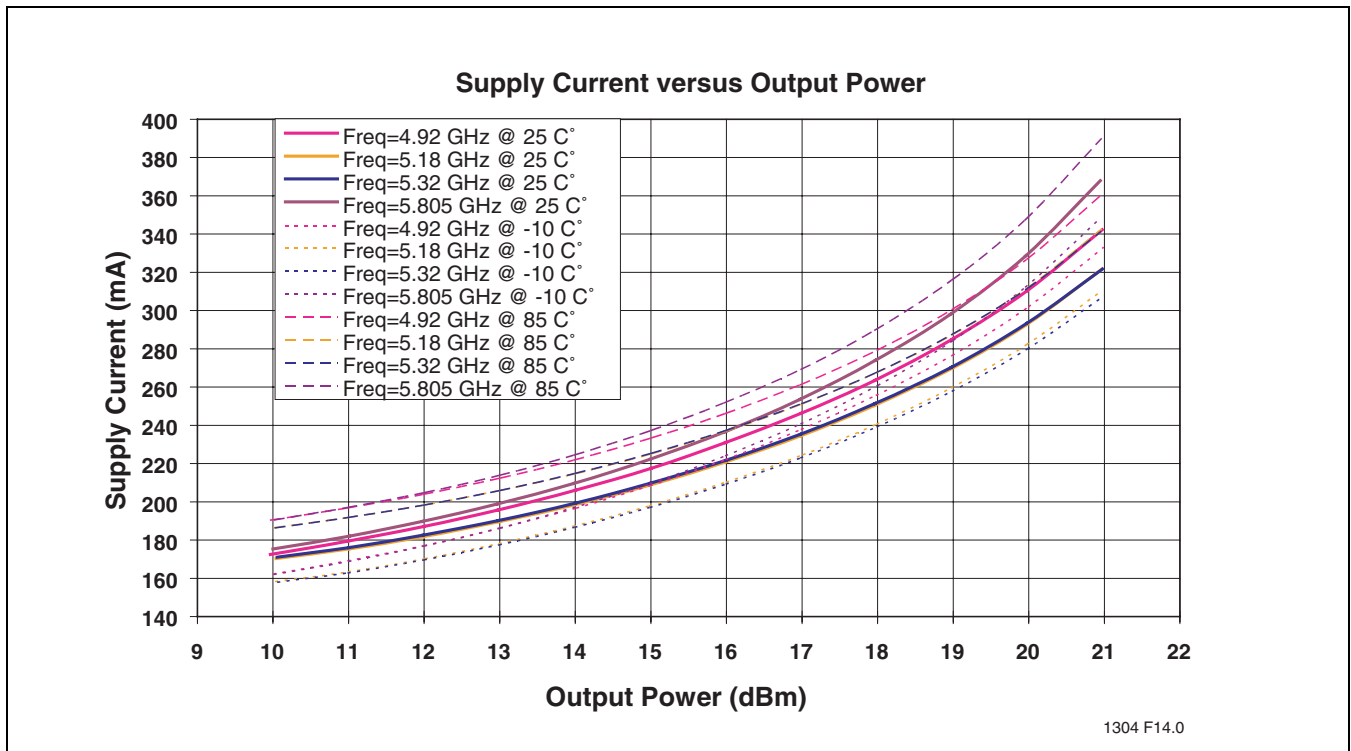


FIGURE 15: High Band Supply Current Versus Output Power

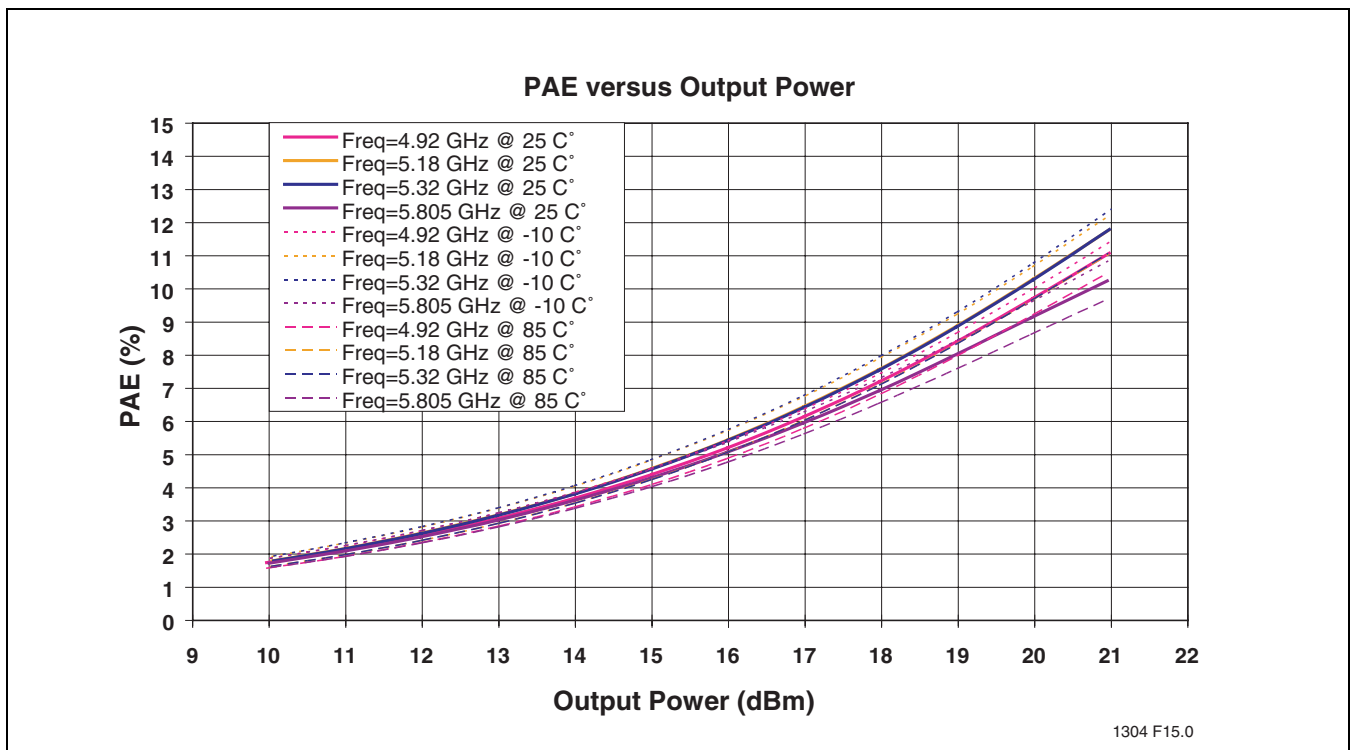


FIGURE 16: High Band PAE versus Output Power

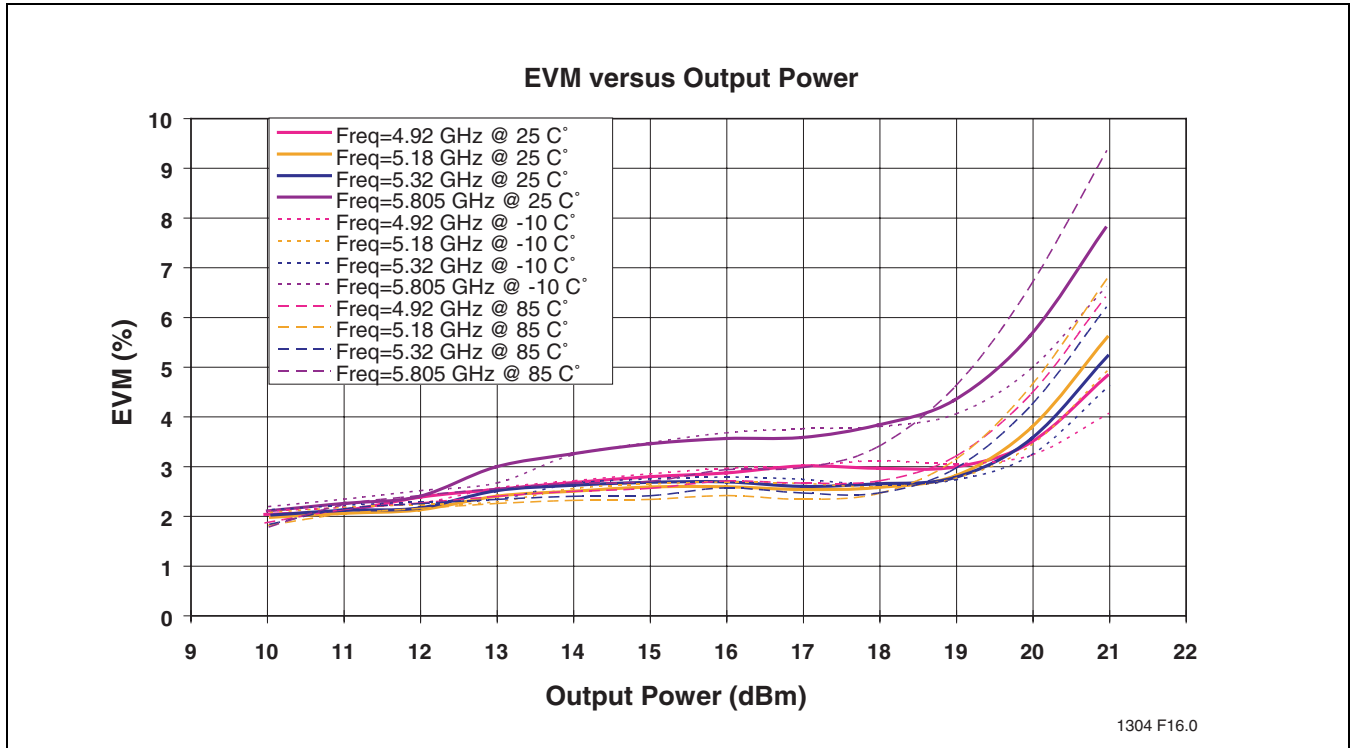


FIGURE 17: High Band EVM versus Output Power

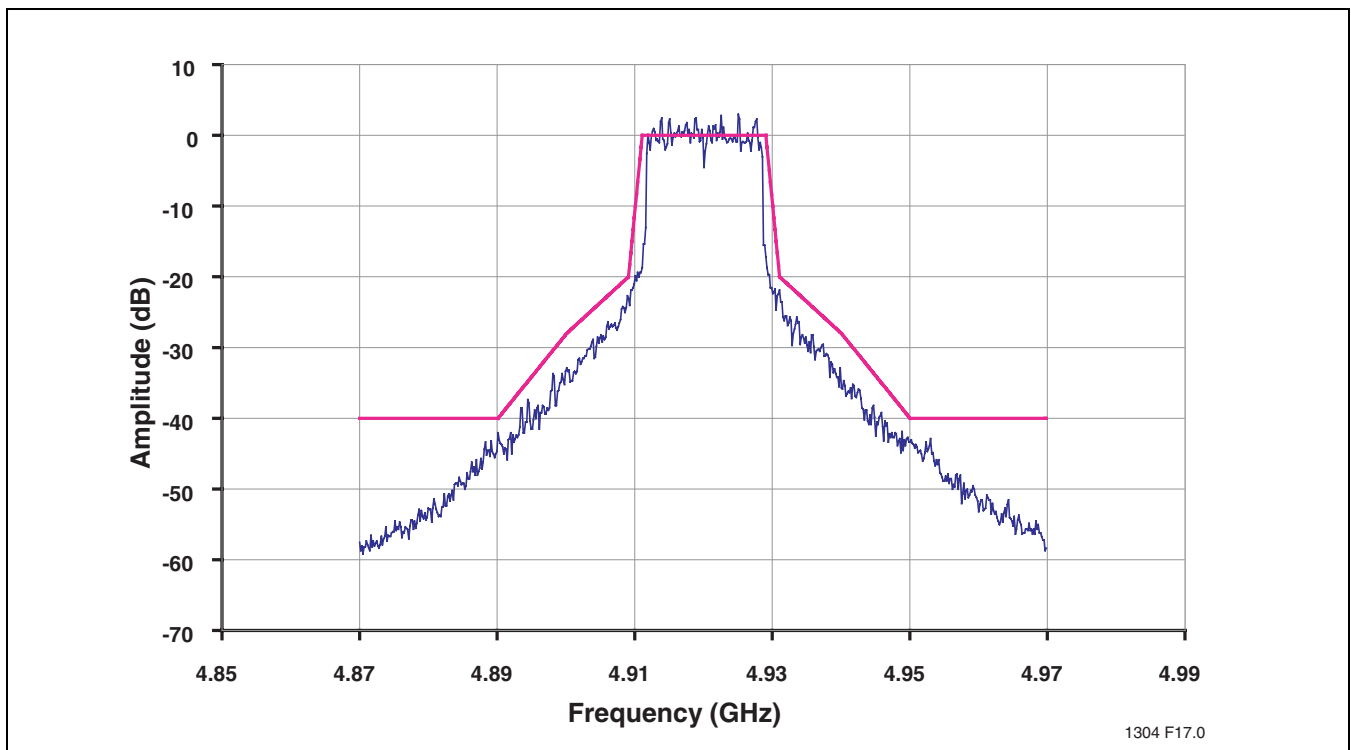
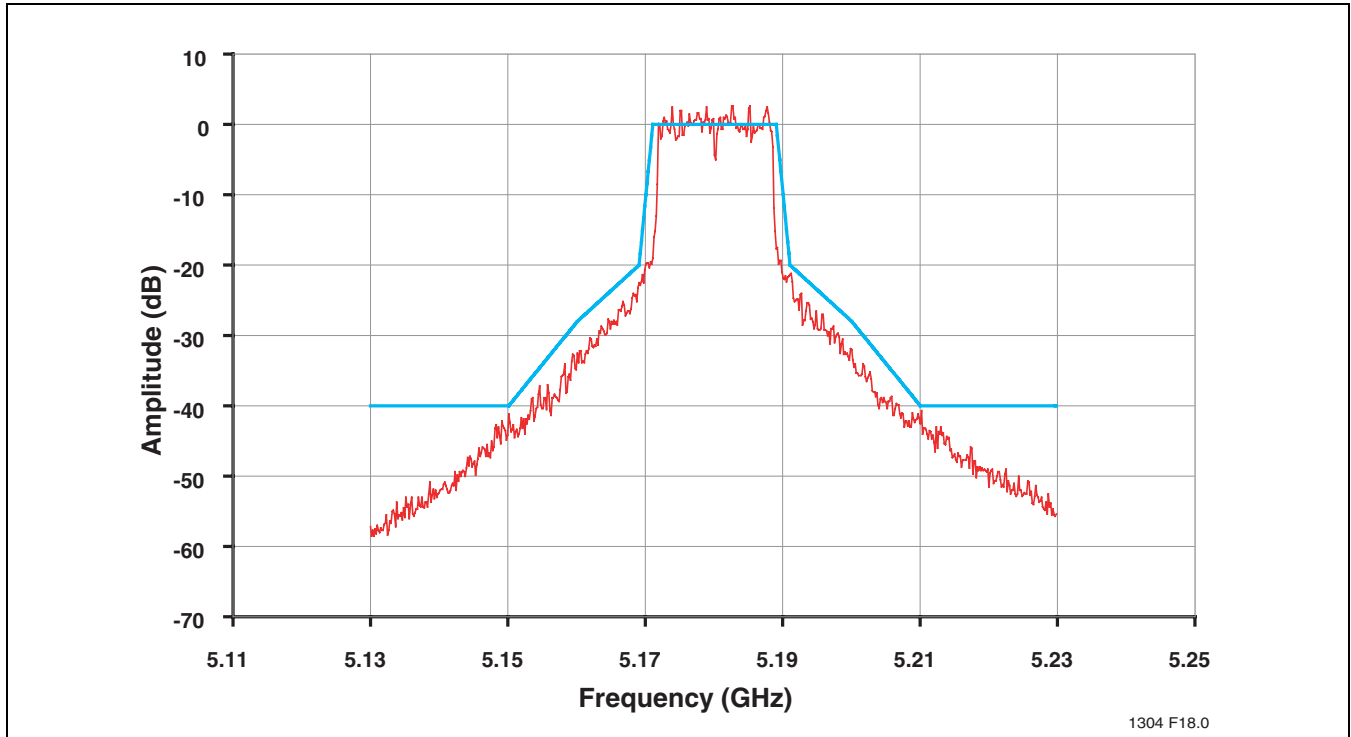


FIGURE 18: High Band 802.11a Spectrum Mask at 4.92 GHz at Output Power 22.5 dBm with DC Current at 410 mA

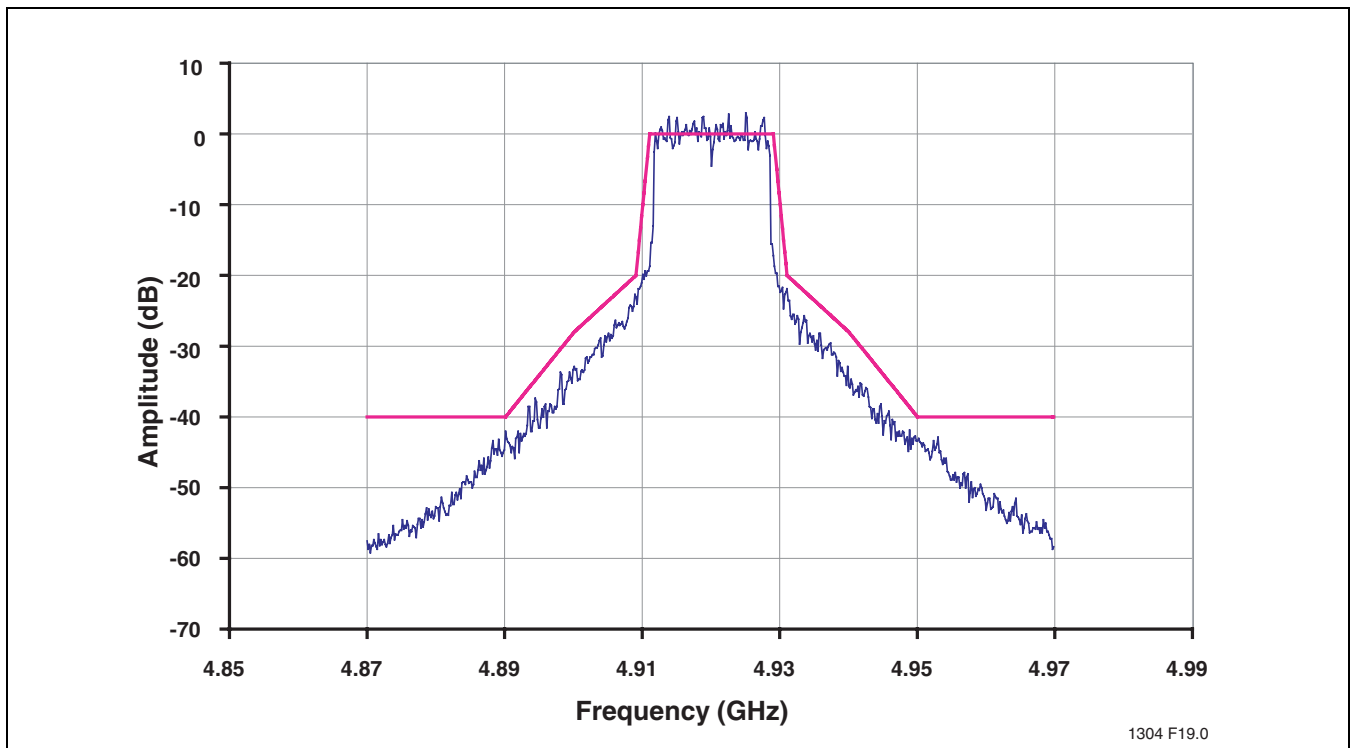


## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications



**FIGURE 19: High Band 802.11a Spectrum Mask at 5.18 GHz at Output Power 22.5 dBm with DC Current at 380 mA**



**FIGURE 20: High Band 802.11a Spectrum Mask at 5.32 GHz at Output Power 22.5 dBm with DC Current at 380 mA**

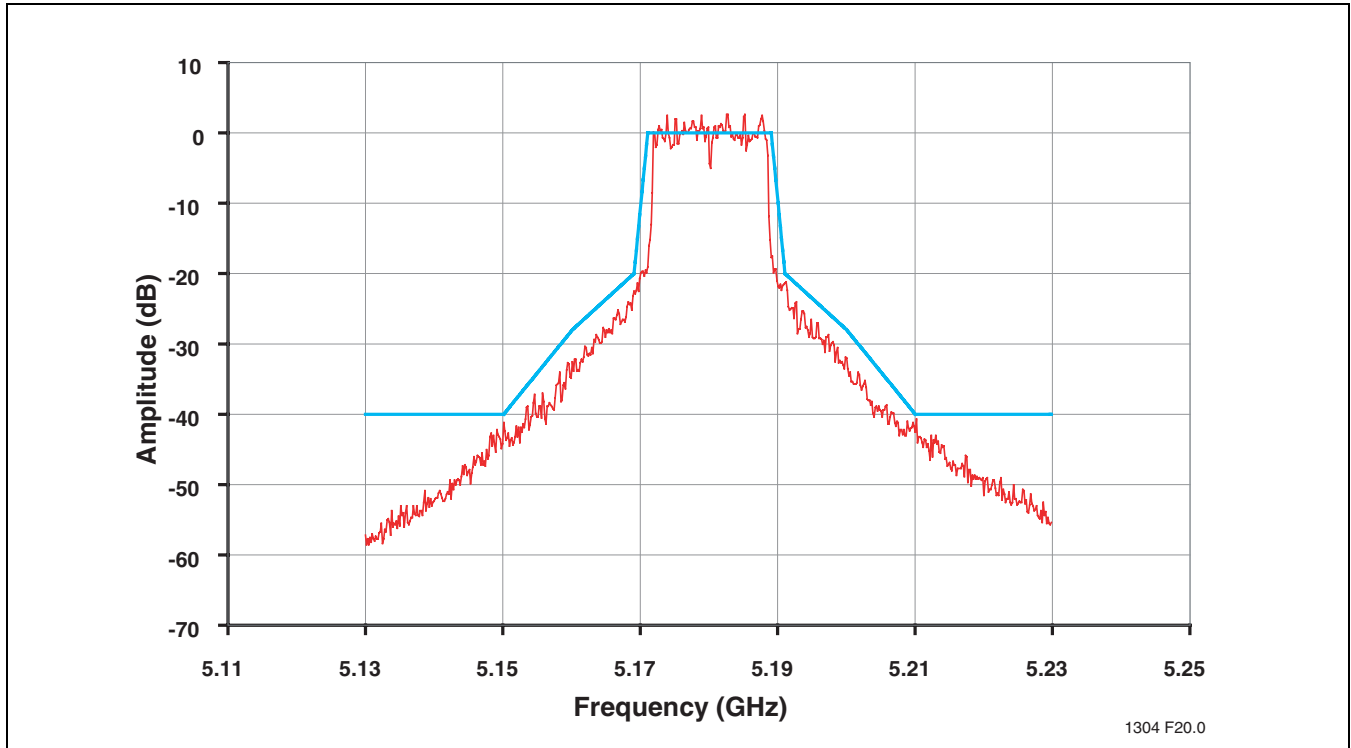


FIGURE 21: High Band 802.11a Spectrum Mask at 5.805 GHz at Output Power 22 dBm with DC Current at 390 mA



Preliminary Specifications

### High Band Power Detector characteristics

Test Conditions: VCC = 3.3V, 54 Mbps 802.11a OFSM Signal

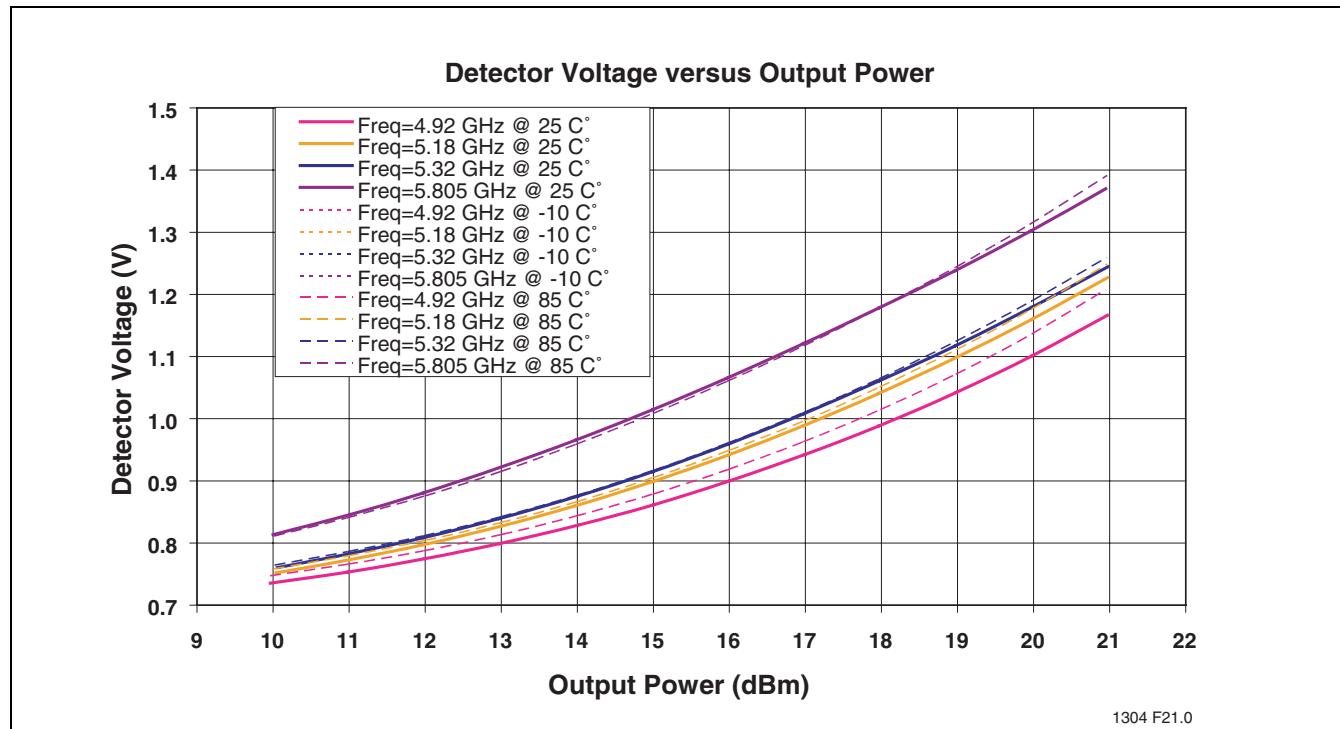
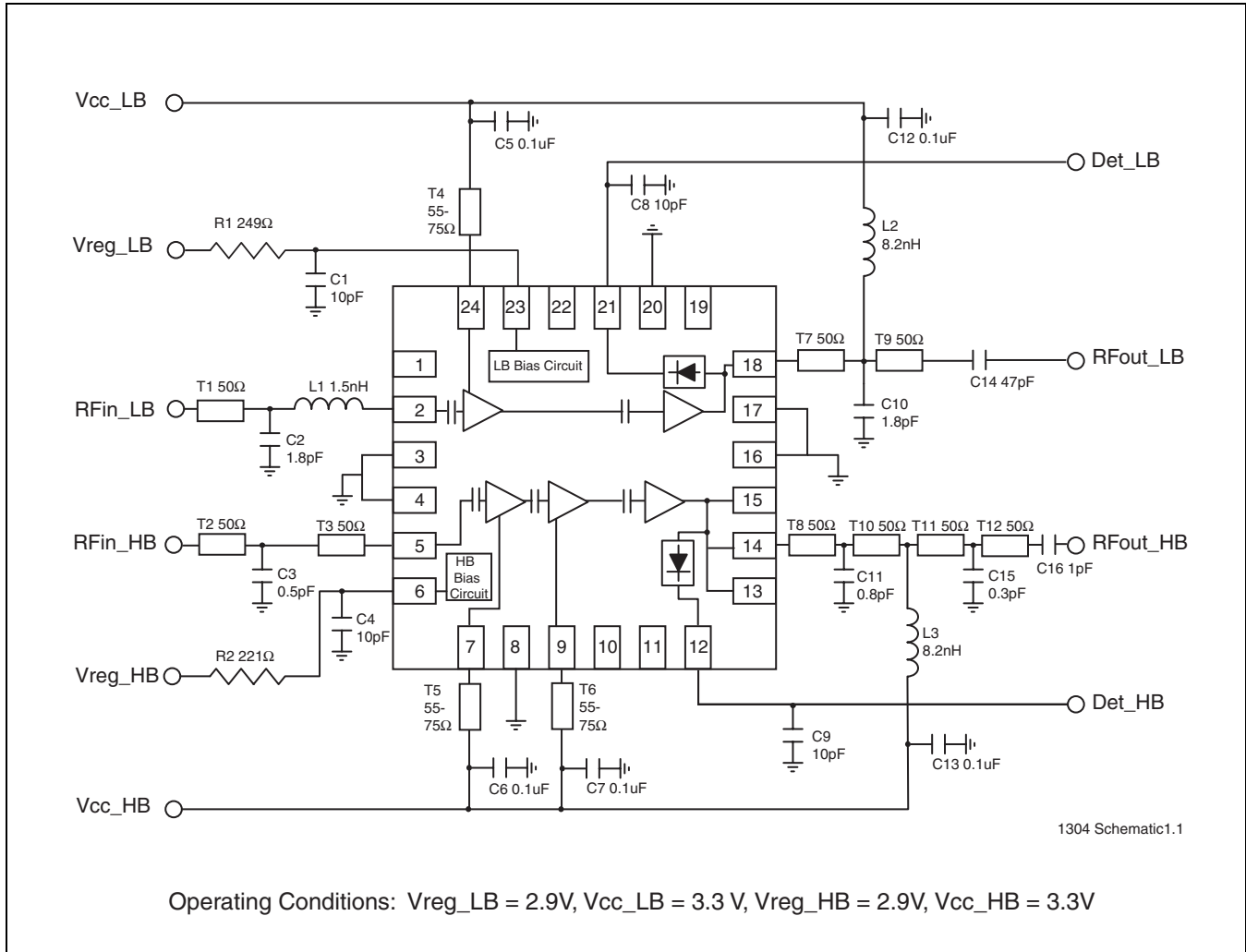


FIGURE 22: High Band Detector Voltage versus Output Power

## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02



Preliminary Specifications



**FIGURE 23: Typical Application Circuit**



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

**TABLE 6: Part List**

| Symbol   | Value  | Note                                                                                                |
|----------|--------|-----------------------------------------------------------------------------------------------------|
| C1       | 10pF   | Larger value can be used if meeting on/off toggling speed requirement of low band on system board   |
| C2       | 1.8pF  | LB input matching                                                                                   |
| C3       | 0.5 pF | HB input matching, no-pop if -6dB input return loss is acceptable                                   |
| C4       | 10pF   | Larger value can be used if meeting on/off toggling speed requirement for high band on system board |
| C5       | 0.1uF  | LB bypassing                                                                                        |
| C6       | 0.1uF  | HB bypassing                                                                                        |
| C7       | 0.1uF  | HB bypassing                                                                                        |
| C8       | 10pF   | LB power detector bypassing/video bandwidth control                                                 |
| C9       | 10pF   | HB power detector bypassing/video bandwidth control                                                 |
| C10      | 1.8pF  | LB band output matching, 1.5~2.0 pF determined by length/impedance of T7, high Q part preferred     |
| C11      | 0.8pF  | HB output matching, high Q cap preferred                                                            |
| C12      | 0.1uF  | LB bypassing, position close to L2                                                                  |
| C13      | 0.1uF  | HB bypassing, position close to L3                                                                  |
| C14      | 47pF   | LB output DC blocking                                                                               |
| C15      | 0.3pF  | HB output matching, high Q cap preferred                                                            |
| C16      | 1pF    | HB output matching / DC blocking                                                                    |
| L1       | 1.5nH  | LB input matching, can be replaced by an 240mil 50Ω microstrip                                      |
| L2       | 8.2nH  | LB output RF chock, coil type preferred                                                             |
| L3       | 8.2nH  | HB output RF chock, coil type preferred                                                             |
| R1       | 249Ω   | Needs adjusting for different Vreg_LB                                                               |
| R2       | 221Ω   | Needs adjusting for different Vreg_HB or 4.9~5.9GHz simultaneous coverage with lower EVM            |
| T1,T2,T9 | 50Ω    | Length not critical                                                                                 |
| T3       | 50Ω    | HB input matching, 50<length<70mil                                                                  |
| T4       | 55~75Ω | Impedance not critical, recommended length=50mil (<130mil should be fine)                           |
| T5       | 55~75Ω | Impedance not critical, length=50mil ± 10mil                                                        |
| T6       | 55~75Ω | Impedance not critical, length=50mil ± 10mil                                                        |
| T7       | 50Ω    | Recommend length =60mil with C10=1.8pF (40<length <120mil OK with C10=1.5~2.0pF)                    |
| T8       | 50Ω    | Critical for HB output matching, length=30mil ± 5mil                                                |
| T10      | 50Ω    | Critical for HB output matching length=45mil ± 5mil                                                 |
| T11      | 50Ω    | Critical for output matching, length=25mil ± 5mil                                                   |
| T12      | 50Ω    | Length = 40mil±5mil                                                                                 |

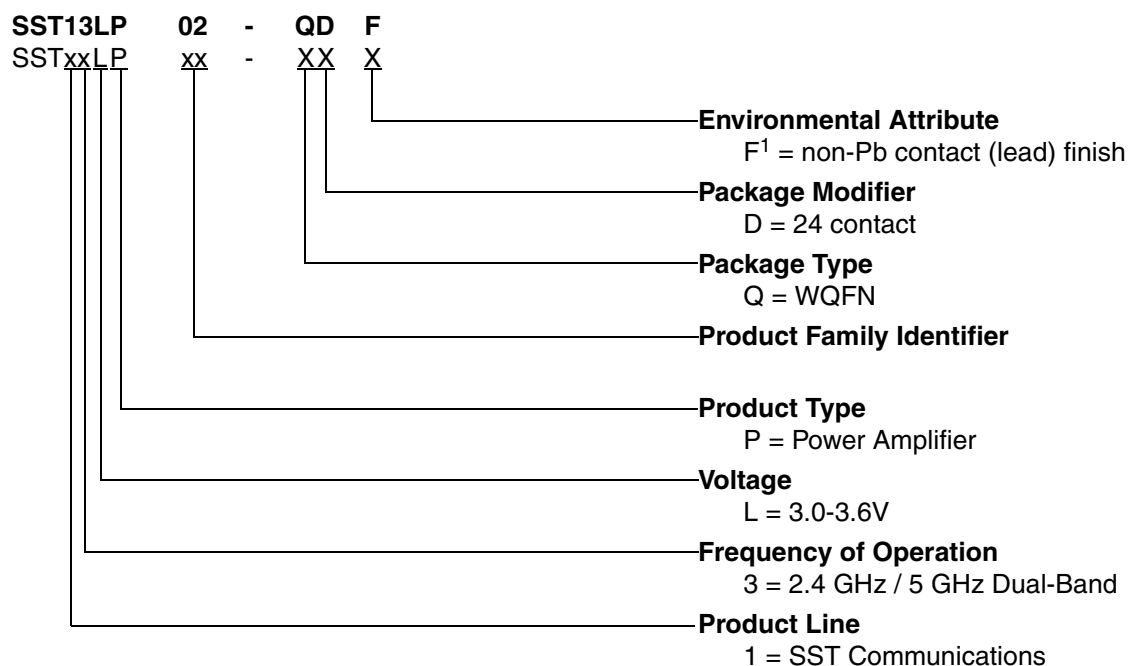
T6.1 1304



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

### Product Ordering Information



1. Environmental suffix "F" denotes non-Pb solder.  
SST non-Pb solder devices are "RoHS Compliant".

### Valid combinations for SST13LP02

SST13LP02-QDF

### SST13LP02 Evaluation Kits

SST13LP02-QDF-K

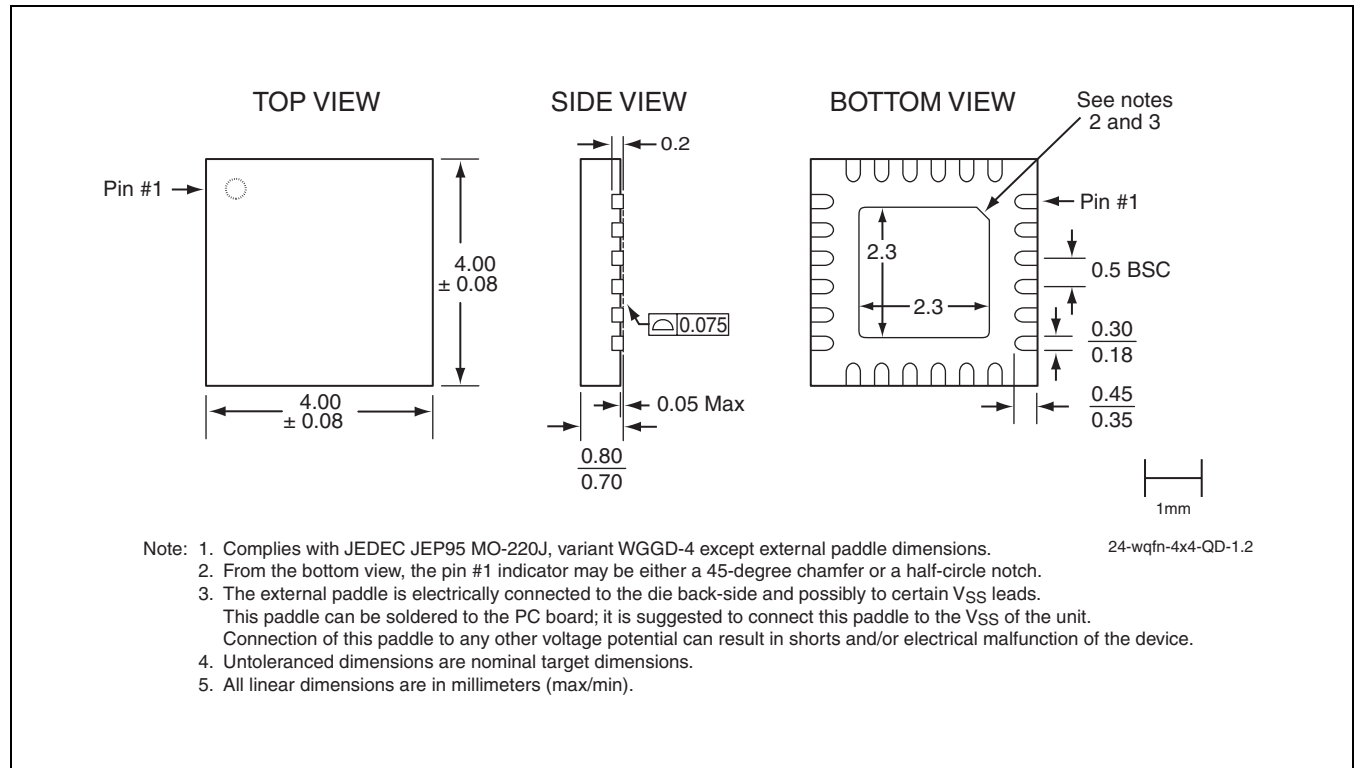
**Note:** Valid combinations are those products in mass production or will be in mass production. Consult your SST sales representative to confirm availability of valid combinations and to determine availability of new combinations.



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

### packaging diagrams



**FIGURE 24: 24-contact Very-very-thin-profile Quad Flat No-lead (WQFN)**  
**SST Package Code: QD**

**TABLE 7: Revision History**

| Revision | Description                                                                                                                                                                          | Date     |
|----------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|
| 00       | • 1304: Conversion from MRD SST13LP02                                                                                                                                                | Nov 2005 |
| 01       | • Updated information for pins 3, 4, 16, and 17 in Figures 1 and 2 and Table 1.<br>• Updated Figure 23.<br>• Revised AC Electrical Characteristics for Configuration tables 3 and 5. | Sep 2006 |



## 2.4-2.5 GHz / 4.9-5.8 GHz Dual-Band Power Amplifier SST13LP02

Preliminary Specifications

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